# N-CHANNEL ENHANCEMENT MODE

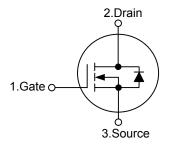
#### **■** DESCRIPTION

The **UT110N03** uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with low gate voltages. This device is suitable for use as a load switch or in PWM applications.

# **■ FEATURES**

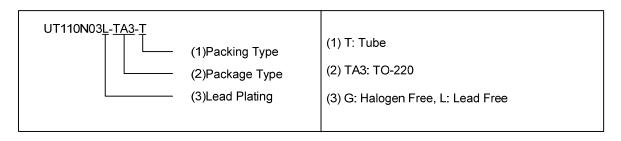
- \* V<sub>DS</sub>(V)=26V
- \* I<sub>D</sub>=110A
- \*  $R_{DS(ON)}$ =4.8m $\Omega$ @ $V_{GS}$ =10 V
- \*  $R_{DS(ON)}$  =7.0m $\Omega$ @ $V_{GS}$ =4.5 V

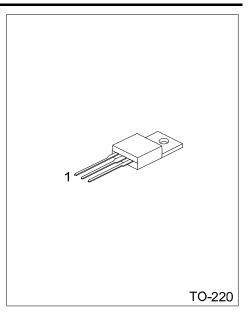
#### ■ SYMBOL



### **■ ORDERING INFORMATION**

Ordering Number		Dookogo	Pin Assignment			Docking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UT110N03L-TA3-T	UT110N03G-TA3-T	TO-220	G	D	S	Tube	





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# ■ **ABSOLUTE MAXIMUM RATINGS** (T<sub>C</sub> =25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Drain-Source Voltage	$V_{DSS}$	26	V
Gate-Source Voltage	$V_{GSS}$	±20	V
Continuous Drain Current	$I_{D}$	110	Α
Pulsed Drain Current (Note 2)	I <sub>DM</sub>	440	Α
Single Pulsed Avalanche Current (Note 3)	I <sub>AS</sub>	35	Α
Single Pulsed Avalanche Energy (Note 3)	E <sub>AS</sub>	875	mJ
Power Dissipation	P <sub>D</sub>	100	W
Junction Temperature	TJ	+175	°C
Strong Temperature	T <sub>STG</sub>	-55 ~ <b>+</b> 175	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Pulse width limited by maximum junction temperature
- 3. L = 0.5mH,  $I_{AS}$  = 35A,  $V_{DD}$  = 25V,  $R_{G}$  = 25 $\Omega$ , Starting  $T_{J}$  = 25 $^{\circ}$ C.

# **■ THERMAL DATA**

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	
Junction to Ambient	$\theta_{JA}$			62.5	°C/W	
Junction to Case	$\theta_{JC}$			1.5	°C/W	

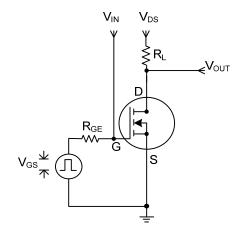
#### ■ ELECTRICAL CHARACTERISTICS (T<sub>J</sub> =25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS N		TYP	MAX	UNIT		
OFF CHARACTERISTICS								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS} = 0V, I_D = 250 \mu A$	26			<b>V</b>		
Drain-Source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =26V,V <sub>GS</sub> =0 V			1	μΑ		
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{DS} = 0V, V_{GS} = \pm 20 V$			±100	nA		
ON CHARACTERISTICS(Note1)								
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	1		3	V		
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	$V_{GS}$ =10V, $I_{D}$ =50 A		3.9	4.8	mΩ		
Static Dialii-Source On-Resistance		$V_{GS}$ =4.5V, $I_{D}$ =40 A		5.2	7.0	mΩ		
DYNAMIC PARAMETERS (Note 2)								
Input Capacitance	C <sub>ISS</sub>			9500		pF		
Output Capacitance	Coss	$V_{DS}$ =15V, $V_{GS}$ =0V, f=1.0MHz		800		pF		
Reverse Transfer Capacitance	C <sub>RSS</sub>			300		pF		
SWITCHING PARAMETERS(Note 2)								
Total Gate Charge	$Q_G$			50	65	nC		
Gate Source Charge	$Q_{GS}$	$V_{DS}$ =15V, $V_{GS}$ =5V, $I_{D}$ =16A		20.8		nC		
Gate Drain Charge	$Q_GD$			19		nC		
Turn-ON Delay Time	t <sub>D(ON)</sub>			25.7	50	ns		
Turn-ON Rise Time	t <sub>R</sub>	$V_{DD}$ =15V, $I_D$ =1A, $R_{GEN}$ =6 $\Omega$		10	20	ns		
Turn-OFF Delay Time	t <sub>D(OFF)</sub>	V <sub>GS</sub> =10 V		128	200	ns		
Turn-OFF Fall-Time	t <sub>F</sub>			34	70	ns		
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS								
Drain-Source Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =20 A,V <sub>GS</sub> =0 V	·-		1.5	V		
Drain-Source Diode Forward Current	Is				90	Α		

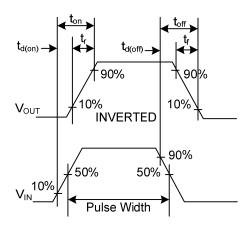
Notes: 1. Pulse Test: Pulse Width<300µs, Duty Cycle<2%

2. Guaranteed by design, not subject to production testing.

# ■ TEST CIRCUIT AND WAVEFORM

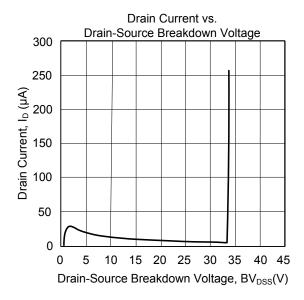


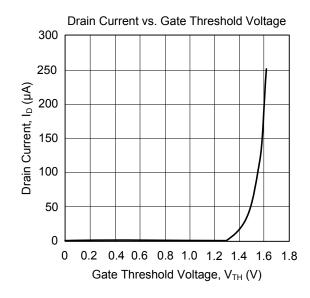
Switching Time Test Circuit

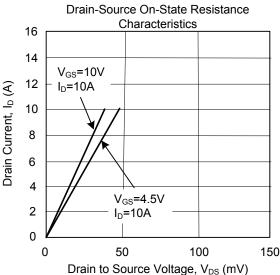


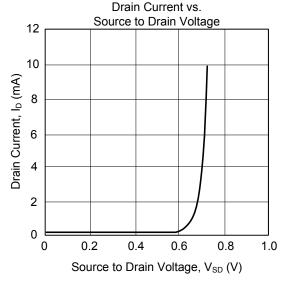
**Switching Waveforms** 

#### **■ TYPICAL CHARACTERISTICS**









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